NSN 5962-01-503-3457

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View Online at https://aerobasegroup.com/nsn/5962-01-503-3457

Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.150 inches and 0.205 inches
Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
C-17a
Features Provided:
Electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Cbbl
Current Rating Per Characteristic:
130.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
15.00 nanoseconds access
Memory Device Type:
Pal
Terminal Type And Quantity:
20 printed circuit
Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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